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# 3 V to 5 V Single Supply, 200 kSPS 12-Bit Sampling ADCs

### AD7853/AD7853L\*

### **FEATURES**

Specified for V<sub>DD</sub> of 3 V to 5.5 V

**Read-Only Operation** 

AD7853-200 kSPS; AD7853L-100 kSPS

System and Self-Calibration with Autocalibration on Power-Up

Low Power:

AD7853: 12 mW ( $V_{DD} = 3 \text{ V}$ ) AD7853L: 4.5 mW ( $V_{DD} = 3 \text{ V}$ )

Automatic Power Down After Conversion (25 μW)

Flexible Serial Interface:

8051/SPI™/QSPI™/μP Compatible 24-Lead DIP, SOIC and SSOP Packages

### **APPLICATIONS**

Battery-Powered Systems (Personal Digital Assistants, Medical Instruments, Mobile Communications) Pen Computers Instrumentation and Control Systems

#### **GENERAL DESCRIPTION**

**High Speed Modems** 

The AD7853/AD7853L are high speed, low power, 12-bit ADCs that operate from a single 3 V or 5 V power supply, the AD7853 being optimized for speed and the AD7853L for low power. The ADC powers up with a set of default conditions at which time it can be operated as a read-only ADC. The ADC contains self-calibration and system-calibration options to ensure accurate operation over time and temperature and have a number of power-down options for low power applications. The part powers up with a set of default conditions and can operate as a read only ADC.

The AD7853 is capable of 200 kHz throughput rate while the AD7853L is capable of 100 kHz throughput rate. The input track-and-hold acquires a signal in 500 ns and features a pseudo-differential sampling scheme. The AD7853/AD7853L voltage range is 0 to  $V_{\rm REF}$  with both straight binary and twos complement output coding. Input signal range is to the supply, and the part is capable of converting full power signals to 100 kHz.

CMOS construction ensures low power dissipation of typically 4.5 mW for normal operation and 1.15 mW in power-down mode, with a throughput rate of 10 kSPS ( $V_{\rm DD}$  = 3 V). The part is available in 24-lead, 0.3 inch wide dual-in-line package (DIP), 24-lead small outline (SOIC) and 24-lead small shrink outline (SSOP) packages.

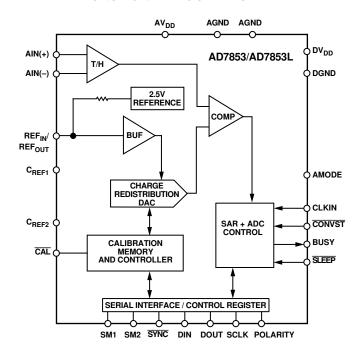
\*Patent pending.

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#### REV. B

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#### FUNCTIONAL BLOCK DIAGRAM



### PRODUCT HIGHLIGHTS

- 1. Specified for 3 V and 5 V supplies.
- 2. Automatic calibration on power-up.
- 3. Flexible power management options including automatic power-down after conversion.
- 4. Operates with reference voltages from 1.2 V to V<sub>DD</sub>.
- 5. Analog input ranges from 0 V to  $V_{DD}$ .
- 6. Self- and system calibration.
- 7. Versatile serial I/O port (SPI/OSPI/8051/µP).
- 8. Lower power version AD7853L.

 $\begin{array}{l} \textbf{AD7853/AD7853L-SPECIFICATIONS}^{1,\ 2} \\ \textbf{External Reference, } f_{\text{CLKIN}} = 4 \text{ MHz } (1.8 \text{ MHz B Grade } (0^{\circ}\text{C to } +70^{\circ}\text{C}), 1 \text{ MHz A and B Grades } (-40^{\circ}\text{C to } +85^{\circ}\text{C}) \text{ for L Version); } f_{\text{SAMPLE}} = 200 \text{ kHz } (1.8 \text{ MHz B Grade } (-40^{\circ}\text{C to } +85^{\circ}\text{C}) \text{ for L Version); } f_{\text{SAMPLE}} = 200 \text{ kHz} \\ \textbf{AD7852} & \textbf{AD7$ (AD7853) 100 kHz (AD7853L);  $\overline{\text{SLEEP}} = \text{Logic High}$ ;  $T_A = T_{\text{MIN}}$  to  $T_{\text{MAX}}$ , unless otherwise noted.) Specifications in () apply to the AD7853L.

Parameter	A Version <sup>1</sup>	B Version <sup>1</sup>	Units	Test Conditions/Comments		
DYNAMIC PERFORMANCE						
Signal to Noise + Distortion Ratio <sup>3</sup>	70	71	dB min	Typically SNR Is 72 dB		
(SNR)				$V_{IN} = 10$ kHz Sine Wave, $f_{SAMPLE} = 200$ kHz (100 kHz)		
Total Harmonic Distortion (THD)	-78	-78	dB max	$V_{IN}$ = 10 kHz Sine Wave, $f_{SAMPLE}$ = 200 kHz (100 kHz)		
Peak Harmonic or Spurious Noise	-78	-78	dB max	$V_{IN}$ = 10 kHz Sine Wave, $f_{SAMPLE}$ = 200 kHz (100 kHz)		
Intermodulation Distortion (IMD)						
Second Order Terms	-78	-80	dB typ	fa = $9.983 \text{ kHz}$ , fb = $10.05 \text{ kHz}$ , $f_{SAMPLE} = 200 \text{ kHz}$ ( $100 \text{ kHz}$ )		
Third Order Terms	-78	-80	dB typ	$fa = 9.983 \text{ kHz}, fb = 10.05 \text{ kHz}, f_{SAMPLE} = 200 \text{ kHz} (100 \text{ kHz})$		
DC ACCURACY						
Resolution	12	12	Bits			
Integral Nonlinearity	±1	±1	LSB max	2.5 V External Reference $V_{DD} = 3 \text{ V}$ , $V_{DD} = 5 \text{ V}$ (B Grade Only)		
	±1	±0.5	LSB max	5 V External Reference $V_{DD} = 5 V$		
		(±1)	LSB max	(L Version, 5 V External Reference, $V_{DD} = 5 \text{ V}$ )		
	(±1)		LSB max	(L Version)		
Differential Nonlinearity	±1	±1	LSB max	Guaranteed No Missed Codes to 12 Bits. 2.5 V External Reference		
				$V_{DD} = 3 \text{ V}, 5 \text{ V}$ External Reference $V_{DD} = 5 \text{ V}$		
Total Unadjusted Error	±1	±1	LSB typ			
Unipolar Offset Error	±1	±1	LSB max	2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External Reference $V_{DD} = 5 \text{ V}$		
Unipolar Offset Error	(±2.5)	(±2.5)	LSB max	(L Versions, 2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External		
Desiries Fell Carla Farra	105	125	I CD	Reference $V_{DD} = 5 V$ )		
Positive Full-Scale Error	±2.5	±2.5	LSB max	2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External Reference $V_{DD} = 5 \text{ V}$		
Positive Full-Scale Error	(±4)	(±4)	LSB max	(L Versions, 2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External		
Negative Full-Scale Error	±2.5	±2.5	LSB max	Reference V <sub>DD</sub> = 5 V)   2.5 V External Reference V <sub>DD</sub> = 3 V, 5 V External Reference V <sub>DD</sub> = 5 V		
Negative Full-Scale Error	(±4)	(±4)	LSB max	(L Versions, 2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External (L Versions), 2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External		
regative run-scale Error	(±4)	(14)	LSB IIIax	Reference $V_{DD} = 5 \text{ V}$ )		
Bipolar Zero Error	±2	±2	LSB max	2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External Reference $V_{DD} = 5 \text{ V}$		
Bipolar Zero Error	(±2.5)	(±2.5)	LSB max	(L Versions, 2.5 V External Reference $V_{DD} = 3 \text{ V}$ , 5 V External		
Espoini Este Ester	(=2.3)	(=2.3)	202	Reference $V_{DD} = 5 \text{ V}$		
ANIAL OC INDUT				,		
ANALOG INPUT	0 to V <sub>REF</sub>	O to V	Volts	i a AIN(+) AIN( ) = 0 to V AIN( ) Can Be Bigged		
Input Voltage Ranges	O to V <sub>REF</sub>	0 to V <sub>REF</sub>	VOILS	i.e., AIN(+) – AIN(-) = 0 to V <sub>REF</sub> , AIN(-) Can Be Biased Up But AIN(+) Cannot Go Below AIN(-)		
	$\pm V_{REF}/2$	$\pm V_{REF}/2$	Volts	i.e., $AIN(+) - AIN(-) = -V_{REF}/2$ to $+V_{REF}/2$ , $AIN(-)$ Should		
	= V KEF/ 2	= * REF' 2	7 0113	Be Biased to +V <sub>REF</sub> /2 and AIN(+) Can Go Below AIN(-) But		
				Cannot Go Below 0 V		
Leakage Current	±1	±1	μA max			
Input Capacitance	20	20	pF typ			
REFERENCE INPUT/OUTPUT						
REF <sub>IN</sub> Input Voltage Range	2.3/V <sub>DD</sub>	2.3/V <sub>DD</sub>	V min/max	Functional from 1.2 V		
Input Impedance	150	150	kΩ typ	T difetional from 1.2 v		
REF <sub>OUT</sub> Output Voltage	2.3/2.7	2.3/2.7	V min/max			
REF <sub>OUT</sub> Tempco	20	20	ppm/°C typ			
			FF			
LOGIC INPUTS						
Input High Voltage, V <sub>INH</sub>		2.4		AV - DV - ACV CCV		
	2.4	2.4	V min	$AV_{DD} = DV_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$		
Innut I aw Valta V	2.1	2.1	V min	$AV_{DD} = DV_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$		
Input Low Voltage, V <sub>INL</sub>	0.8	0.8	Vmorr	AV - DV - 45 V to 55 V		
	0.8	0.8	V max	$AV_{DD} = DV_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$		
Input Current, I <sub>IN</sub>	0.6	0.6	V max	$AV_{DD} = DV_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$ Typically 10 nA, $V_{IN} = 0 \text{ V or } V_{DD}$		
Input Current, I <sub>IN</sub> Input Capacitance, C <sub>IN</sub> <sup>4</sup>	±10 10	±10 10	μA max pF max	1 ypicany 10 ma, vm - 0 v or vDD		
mput Capacitance, CIN	10	10	br. max			

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Parameter	A Version <sup>1</sup>	B Version <sup>1</sup>	Units	Test Conditions/Comments
LOGIC OUTPUTS				
Output High Voltage, VOH				$I_{SOURCE} = 200 \mu\text{A}$
1 8 8 9 91	4	4	V min	$AV_{DD} = DV_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$
	2.4	2.4	V min	$AV_{DD} = DV_{DD} = 3.0 \text{ V to } 3.6 \text{ V}$
Output Low Voltage, Vol.	0.4	0.4	V max	$I_{SINK} = 0.8 \text{ mA}$
Floating-State Leakage Current	±10	±10	μA max	
Floating-State Output Capacitance <sup>4</sup>	10	10	pF max	
Output Coding		ht (Natural) Binai	ry	Unipolar Input Range
	Two	os Complement		Bipolar Input Range
CONVERSION RATE				
Conversion Time	4.6 (18)	4.6 (18)	μs max	(L Versions Only, -40°C to +85°C, 1 MHz CLKIN)
		(10)	μs max	(L Versions Only, 0°C to +70°C, 1.8 MHz CLKIN)
Track/Hold Acquisition Time	0.4 (1)	0.4 (1)	μs min	(L Versions Only)
POWER REQUIREMENTS				
$AV_{DD}$ , $DV_{DD}$	+3.0/+5.5	+3.0/+5.5	V min/max	
$I_{\mathrm{DD}}$				
Normal Mode <sup>5</sup>	6 (1.9)	6 (1.9)	mA max	$AV_{DD} = DV_{DD} = 4.5 \text{ V to } 5.5 \text{ V. Typically } 4.5 \text{ mA } (1.5);$
	5.5 (1.9)	5.5 (1.9)	mA max	$AV_{DD} = DV_{DD} = 3.0 \text{ V to } 3.6 \text{ V. Typically } 4.0 \text{ mA } (1.5 \text{ mA})$
Sleep Mode <sup>6</sup>				
With External Clock On	10	10	μA typ	Full Power-Down. Power Management Bits in Control Register
				Set as $PMGT1 = 1$ , $PMGT0 = 0$
	400	400	μA typ	Partial Power-Down. Power Management Bits in Control
				Register Set as PMGT1 = 1, PMGT0 = 1
With External Clock Off	5	5	μA max	Typically 1 µA. Full-Power Down. Power Management Bits in
				Control Register Set as PMGT1 = 1, PMGT0 = 0
	200	200	μA typ	Partial Power-Down. Power Management Bits in Control
	22 (42 5)	22 (12 5)		Register Set as PMGT1 = 1, PMGT0 = 1
Normal Mode Power Dissipation	33 (10.5)	33 (10.5)	mW max	$V_{DD} = 5.5 \text{ V}$ : Typically 25 mW (8); $\overline{\text{SLEEP}} = V_{DD}$
01 11 12 12:	20 (6.85)	20 (6.85)	mW max	$V_{DD} = 3.6 \text{ V: Typically } 15 \text{ mW } (5.4); \overline{\text{SLEEP}} = V_{DD}$
Sleep Mode Power Dissipation With External Clock On	==			V - 55 V SI FED - 0 V
With External Clock On	55	55	μW typ	$V_{DD} = 5.5 \text{ V}; \overline{\text{SLEEP}} = 0 \text{ V}$ $V_{DD} = 3.6 \text{ V}; \overline{\text{SLEEP}} = 0 \text{ V}$
With External Clock Off	36 27.5	36	μW typ μW max	$V_{DD} = 5.6 \text{ V}$ ; SLEEP = 0 V $V_{DD} = 5.5 \text{ V}$ : Typically $5.5 \mu\text{W}$ ; SLEEP = 0 V
With External Clock Off	18	27.5 18	μW max	$V_{DD} = 3.6 \text{ V}$ : Typically 3.6 $\mu$ W; SLEEP = 0 V $V_{DD} = 3.6 \text{ V}$ : Typically 3.6 $\mu$ W; SLEEP = 0 V
	10	10	μw max	VDD - 3.0 v. Typicany 3.0 μw, 3LLEET - 0 v
SYSTEM CALIBRATION				
Offset Calibration Span <sup>7</sup>	$+0.05 \times V_{REF}/-0.05 \times V_{REF}$		V max/min	Allowable Offset Voltage Span for Calibration
Gain Calibration Span <sup>7</sup>	$+1.025 \times V_{REF}$	$-0.975 \times V_{REF}$	V max/min	Allowable Full-Scale Voltage Span for Calibration

Specifications subject to change without notice.

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<sup>&</sup>lt;sup>1</sup>Temperature ranges as follows: A, B Versions, -40°C to +85°C. For L Versions, A and B Versions f<sub>CLKIN</sub> = 1 MHz over -40°C to +85°C temperature range,

B Version  $f_{CLKIN}$  = 1.8 MHz over 0°C to +70°C temperature range.

<sup>&</sup>lt;sup>2</sup>Specifications apply after calibration.

<sup>&</sup>lt;sup>3</sup>SNR calculation includes distortion and noise components.

<sup>&</sup>lt;sup>4</sup>Sample tested @ +25°C to ensure compliance.

<sup>&</sup>lt;sup>5</sup>All digital inputs @ DGND except for CONVST, SLEEP, CAL, and SYNC @ DV<sub>DD</sub>. No load on the digital outputs. Analog inputs @ AGND.

<sup>6</sup>CLKIN @ DGND when external clock off. All digital inputs @ DGND except for CONVST, SLEEP, CAL, and SYNC @ DV<sub>DD</sub>. No load on the digital outputs. Analog inputs @ AGND.

<sup>&</sup>lt;sup>7</sup>The offset and gain calibration spans are defined as the range of offset and gain errors that the AD7853/AD7853L can calibrate. Note also that these are voltage spans and are not absolute voltages (i.e., the allowable system offset voltage presented at AIN(+) for the system offset error to be adjusted out will be AIN(-)  $\pm 0.05 \times V_{REF}$ , and the allowable system full-scale voltage applied between AIN(+) and AIN(-) for the system full-scale voltage error to be adjusted out will be  $V_{REF} \pm 0.025 \times V_{REF}$ . This is explained in more detail in the calibration section of the data sheet.

TIMING SPECIFICATIONS  $^1$  (AV<sub>DD</sub> = DV<sub>DD</sub> = +3.0 V to +5.5 V;  $f_{CLKIN}$  = 4 MHz for AD7853 and 1.8/1 MHz for AD7853L;  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted)

	Limit at T <sub>MIN</sub> , T <sub>MAX</sub> (A, B Versions)					
Parameter	5 V	3 V	Units	Description		
$f_{\text{CLKIN}}^2$	500	500	kHz min	Master Clock Frequency		
ozau.	4	4	MHz max	* *		
	1.8	1.8	MHz max	L Version, 0°C to +70°C, B Grade Only		
	1	1	MHz max	L Version, –40°C to +85°C		
$f_{SCLK}^{3}$	4	4	MHz max	Interface Modes 1, 2, 3 (External Serial Clock)		
	f <sub>CLKIN</sub>	$f_{CLKIN}$	MHz max	Interface Modes 4, 5 (Internal Serial Clock)		
$t_1^4$	100	100	ns min	CONVST Pulsewidth		
$t_2$	50	90	ns max	CONVST↓ to BUSY↑ Propagation Delay		
t <sub>CONVERT</sub>	4.6	4.6	μs max	Conversion Time = 18 t <sub>CLKIN</sub>		
	10 (18)	10 (18)	μs max	L Version 1.8 (1) MHz CLKIN. Conversion Time = 18 t <sub>CLKIN</sub>		
$t_3$	-0.4 t <sub>SCLK</sub>	−0.4 t <sub>SCLK</sub>	ns min	SYNC↓ to SCLK↓ Setup Time (Noncontinuous SCLK Input)		
	$\mp 0.4 t_{SCLK}$	$\mp 0.4 t_{SCLK}$	ns min/max	SYNC↓ to SCLK↓ Setup Time (Continuous SCLK Input)		
$t_4$	0.6 t <sub>SCLK</sub>	0.6 t <sub>SCLK</sub>	ns min	SYNC↓ to SCLK↓ Setup Time. Interface Mode 4 Only		
t <sub>5</sub> <sup>5</sup>	50	90	ns max	Delay from SYNC↓ until DOUT 3-State Disabled		
$t_{4}$ $t_{5}^{5}$ $t_{5A}^{5}$ $t_{6}^{5}$	50	90	ns max	Delay from SYNC↓ until DIN 3-State Disabled		
$t_6^5$	75	115	ns max	Data Access Time After SCLK↓		
$t_7$	40	60	ns min	Data Setup Time Prior to SCLK↑		
$t_{8}$ $t_{9}^{6}$ $t_{10}^{6}$	20	30	ns min	Data Valid to SCLK Hold Time		
$t_9^6$	0.4 t <sub>SCLK</sub>	0.4 t <sub>SCLK</sub>	ns min	SCLK High Pulsewidth (Interface Modes 4 and 5)		
$t_{10}^{6}$	0.4 t <sub>SCLK</sub>	0.4 t <sub>SCLK</sub>	ns min	SCLK Low Pulsewidth (Interface Modes 4 and 5)		
t <sub>11</sub>	30	50	ns min	$SCLK \uparrow to \overline{SYNC} \uparrow Hold Time (Noncontinuous SCLK)$		
	30/0.4 t <sub>SCLK</sub>	50/0.4 t <sub>SCLK</sub>	ns min/max	(Continuous SCLK) Does Not Apply to Interface Mode 3		
$t_{11\underline{A}}$	50	50	ns max	SCLK↑ to SYNC↑ Hold Time		
$t_{12}^{7}$	50	50	ns max	Delay from SYNC↑ until DOUT 3-State Enabled		
$t_{13} \\ t_{14}^{8}$	90	130	ns max	Delay from SCLK↑ to DIN Being Configured as Output		
$t_{14}^{8}$	50	90	ns max	Delay from SCLK↑ to DIN Being Configured as Input		
t <sub>15</sub>	2.5 t <sub>CLKIN</sub>	2.5 t <sub>CLKIN</sub>	ns max	<u>CAL</u> ↑ to BUSY↑ Delay		
t <sub>16</sub>	2.5 t <sub>CLKIN</sub>	2.5 t <sub>CLKIN</sub>	ns max	CONVST↓ to BUSY↑ Delay in Calibration Sequence		
t <sub>CAL</sub> <sup>9</sup>	31.25	31.25	ms typ	Full Self-Calibration Time, Master Clock Dependent		
0				(125013 t <sub>CLKIN</sub> )		
t <sub>CAL1</sub> <sup>9</sup>	27.78	27.78	ms typ	Internal DAC Plus System Full-Scale Cal Time, Master Clock		
0				Dependent (111114 t <sub>CLKIN</sub> )		
$t_{CAL2}^{9}$	3.47	3.47	ms typ	System Offset Calibration Time, Master Clock Dependent		
				(13899 t <sub>CLKIN</sub> )		

#### NOTES

Descriptions that refer to SCLK↑ (rising) or SCLK↓ (falling) edges here are with the POLARITY pin HIGH. For the POLARITY pin LOW then the opposite edge of

Specifications subject to change without notice.

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<sup>&</sup>lt;sup>1</sup>Sample tested at +25°C to ensure compliance. All input signals are specified with tr = tf = 5 ns (10% to 90% of V<sub>DD</sub>) and timed from a voltage level of 1.6 V. See Table X and timing diagrams for different interface modes and calibration.

<sup>&</sup>lt;sup>2</sup>Mark/Space ratio for the master clock input is 40/60 to 60/40.

<sup>&</sup>lt;sup>3</sup>For Interface Modes 1, 2, 3 the SCLK max frequency will be 4 MHz. For Interface Modes 4 and 5 the SCLK will be an output and the frequency will be f CLKIN. <sup>4</sup>The CONVST pulsewidth will apply here only for normal operation. When the part is in power-down mode, a different CONVST pulsewidth will apply (see Power-Down section).

 $<sup>^5</sup>$ Measured with the load circuit of Figure 1 and defined as the time required for the output to cross 0.8 V or 2.4 V.

<sup>&</sup>lt;sup>6</sup>For self-clocking mode (Interface Modes 4, 5) the nominal SCLK high and low times will be 0.5 t<sub>SCLK</sub> = 0.5 t<sub>CLKIN</sub>.

<sup>7</sup>t<sub>12</sub> is derived form the measured time taken by the data outputs to change 0.5 V when loaded with the circuit of Figure 1. The measured number is then extrapolated back to remove the effects of charging or discharging the 100 pF capacitor. This means that the time, t<sub>12</sub>, quoted in the timing characteristics is the true bus relinquish time of the part and is independent of the bus loading.

st<sub>14</sub> is derived form the measured time taken by the data outputs to change 0.5 V when loaded with the circuit of Figure 1. The measured number is then extrapolated back to remove the effects of charging or discharging the 100 pF capacitor. This means that the time quoted in the timing characteristics is the true delay of the part in turning off the output drivers and configuring the DIN line as an input. Once this time has elapsed the user can drive the DIN line knowing that a bus conflict will

<sup>&</sup>lt;sup>9</sup>The typical time specified for the calibration times is for a master clock of 4 MHz. For the L version the calibration times will be longer than those quoted here due to the 1.8/1 MHz master clock.

### TYPICAL TIMING DIAGRAMS

Figure 2 and 3 show typical read and write timing diagrams. Figure 2 shows the reading and writing after conversion in Interface Modes 2 and 3. To attain the maximum sample rate of 100 kHz (AD7853L) or 200 kHz (AD7853) in Interface Modes 2 and 3, reading and writing must be performed during conversion. Figure 3 shows the timing diagram for Interface Modes 4 and 5 with sample rate of 100 kHz (AD7853L) or 200 kHz (AD7853). At least 400 ns acquisition time must be allowed (the time from the falling edge of BUSY to the next rising edge of  $\overline{\text{CONVST}}$ ) before the next conversion begins to ensure that the part is settled to the 12-bit level. If the user does not want to provide the  $\overline{\text{CONVST}}$  signal, the conversion can be initiated in software by writing to the control register.

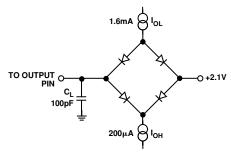


Figure 1. Load Circuit for Digital Output Timing Specifications

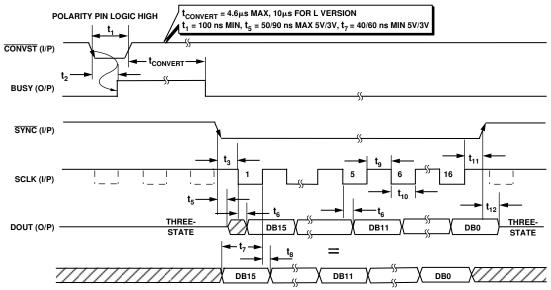


Figure 2. AD7853/AD7853L Timing Diagram (Typical Read and Write Operation for Interface Modes 2, 3)

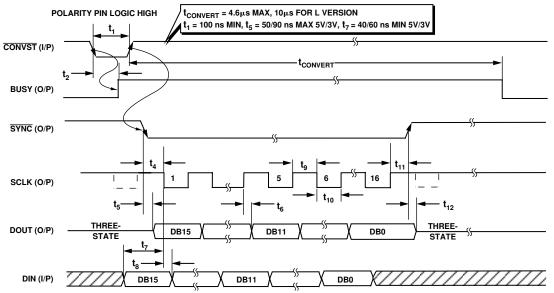


Figure 3. AD7853/AD7853L Timing Diagram (Typical Read and Write Operation for Interface Modes 4, 5)

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### ABSOLUTE MAXIMUM RATINGS1

 $(T_A = +25^{\circ}C \text{ unless otherwise noted})$ 

$\begin{array}{cccccccccccccccccccccccccccccccccccc$
$AV_{DD}$ to $DV_{DD}$
Analog Input Voltage to AGND $-0.3 \text{ V}$ to AV <sub>DD</sub> + 0.3 V
Digital Input Voltage to DGND0.3 V to DV <sub>DD</sub> + 0.3 V
Digital Output Voltage to DGND $-0.3 \text{ V}$ to DV <sub>DD</sub> + 0.3 V
$REF_{IN}/REF_{OUT}$ to AGND0.3 V to $AV_{DD}$ + 0.3 V
Input Current to Any Pin Except Supplies <sup>2</sup> $\pm 10 \text{ mA}$
Operating Temperature Range
Commercial (A, B Versions)40°C to +85°C
Storage Temperature Range65°C to +150°C
Junction Temperature+150°C
Plastic DIP Package, Power Dissipation 450 mW
$\theta_{JA}$ Thermal Impedance
$\theta_{JC}$ Thermal Impedance 34.7°C/W
Lead Temperature, (Soldering, 10 sec) +260°C
SOIC, SSOP Package, Power Dissipation 450 mW
$\theta_{JA}$ Thermal Impedance 75°C/W (SOIC) 115°C/W (SSOP)
$\theta_{\text{JC}}$ Thermal Impedance 25°C/W (SOIC) 35°C/W (SSOP)
Lead Temperature, Soldering
Vapor Phase (60 sec)+215°C
Infrared (15 sec) +220°C
ESD

#### NOTES

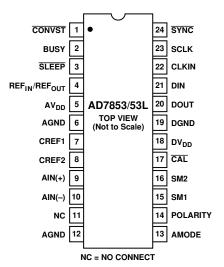
### **ORDERING GUIDE**

Model	Linearity Error (LSB) <sup>1</sup>	Power Dissipation (mW)	Package Options <sup>2</sup>
AD7853AN	±1	20	N-24
AD7853BN	$\pm 1/2$	20	N-24
$AD7853LAN^3$	±1	6.85	N-24
AD7853LBN <sup>3</sup>	±1	6.85	N-24
AD7853AR	±1	20	R-24
AD7853BR	$\pm 1/2$	20	R-24
AD7853LAR <sup>3</sup>	±1	6.85	R-24
AD7853LBR <sup>3</sup>	±1	6.85	R-24
AD7853ARS	±1	6.85	RS-24
AD7853LARS <sup>3</sup>	±1	6.85	RS-24
EVAL-AD7853CB <sup>4</sup>			
EVAL-CONTROL BO	DARD⁵		

### NOTES

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### PIN CONFIGURATIONS DIP, SOIC AND SSOP



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<sup>&</sup>lt;sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

<sup>&</sup>lt;sup>2</sup>Transient currents of up to 100 mA will not cause SCR latch-up.

<sup>&</sup>lt;sup>1</sup>Linearity error refers to the integral linearity error.

 $<sup>^{2}</sup>$ N = Plastic DIP; R = SOIC; RS = SSOP.

<sup>&</sup>lt;sup>3</sup>L signifies the low power version.

<sup>&</sup>lt;sup>4</sup>This can be used as a stand-alone evaluation board or in conjunction with the EVAL-CONTROL BOARD for evaluation/demonstration purposes.

<sup>&</sup>lt;sup>5</sup>This board is a complete unit allowing a PC to control and communicate with all Analog Devices, Inc. evaluation boards ending in the CB designators.

### PIN FUNCTION DESCRIPTIONS

Pin	Mnemonic	Description
1	CONVST	Convert Start. Logic Input. A low to high transition on this input puts the track/hold into its hold mode and starts conversion. When this input is not used, it should be tied to DV <sub>DD</sub> .
2	BUSY	Busy Output. The busy output is triggered high by the falling edge of $\overline{CONVST}$ or rising edge of $\overline{CAL}$ , and remains high until conversion is completed. BUSY is also used to indicate when the AD7853/AD7853L has completed its on-chip calibration sequence.
3	SLEEP	Sleep Input/Low Power Mode. A Logic 0 initiates a sleep and all circuitry is powered down including the internal voltage reference provided there is no conversion or calibration being performed. Calibration data is retained. A Logic 1 results in normal operation. See Power-Down section for more details.
4	REF <sub>IN</sub> / REF <sub>OUT</sub>	Reference Input/Output. This pin is connected to the internal reference through a series resistor and is the reference source for the analog-to-digital converter. The nominal reference voltage is 2.5 V and this appears at the pin. This pin can be overdriven by an external reference or can be taken as high as $AV_{DD}$ . When this pin is tied to $AV_{DD}$ , or when an externally applied reference approaches $AV_{DD}$ , the $C_{REF1}$ pin should also be tied to $AV_{DD}$ .
5	$AV_{DD}$	Analog Positive Supply Voltage, +3.0 V to +5.5 V.
6, 12	AGND	Analog Ground. Ground reference for track/hold, reference and DAC.
7	C <sub>REF1</sub>	Reference Capacitor (0.1 µF multilayer ceramic). This external capacitor is used as a charge source for the internal DAC. The capacitor should be tied between the pin and AGND.
8	$C_{REF2}$	Reference Capacitor (0.01 $\mu$ F ceramic disc). This external capacitor is used in conjunction with the on-chip reference. The capacitor should be tied between the pin and AGND.
9	AIN(+)	Analog Input. Positive input of the pseudo-differential analog input. Cannot go below AGND or above AV <sub>DD</sub> at any time, and cannot go below AIN(–) when the unipolar input range is selected.
10	AIN(-)	Analog Input. Negative input of the pseudo-differential analog input. Cannot go below AGND or above $AV_{\mathrm{DD}}$ at any time.
11	NC	No Connect Pin.
13	AMODE	Analog Mode Pin. This pin allows two different analog input ranges to be selected. A Logic 0 selects range 0 to $V_{REF}$ (i.e., $AIN(+) - AIN(-) = 0$ to $V_{REF}$ ). In this case $AIN(+)$ cannot go below $AIN(-)$ and $AIN(-)$ cannot go below AGND. A Logic 1 selects range $-V_{REF}/2$ to $+V_{REF}/2$ (i.e., $AIN(+) - AIN(-) = -V_{REF}/2$ to $+V_{REF}/2$ ). In this case $AIN(+)$ cannot go below AGND so that $AIN(-)$ needs to be biased to $+V_{REF}/2$ to allow $AIN(+)$ to go from 0 V to $+V_{REF}$ V.
14	POLARITY	Serial Clock Polarity. This pin determines the active edge of the serial clock (SCLK). Toggling this pin will reverse the active edge of the serial clock (SCLK). A Logic 1 means that the serial clock (SCLK) idles high and a Logic 0 means that the serial clock (SCLK) idles low. It is best to refer to the timing diagrams and Table IX for the SCLK active edges.
15	SM1	Serial Mode Select Pin. This pin is used in conjunction with the SM2 pin to give different modes of operation as described in Table X.
16	SM2	Serial Mode Select Pin. This pin is used in conjunction with the SM1 pin to give different modes of operation as described in Table X.
17	CAL	Calibration Input. This pin has an internal pull-up current source of 0.15 µA. A Logic 0 on this pin resets all calibration control logic and initiates a calibration on its rising edge. There is the option of connecting a 10 nF capacitor from this pin to DGND to allow for an automatic self-calibration on power-up. This input overrides all other internal operations. If the autocalibration is not required, this pin should be tied to a logic high.
18	$\mathrm{DV}_{\mathrm{DD}}$	Digital Supply Voltage, +3.0 V to +5.5 V.
19	DGND	Digital Ground. Ground reference point for digital circuitry.
20	DOUT	Serial Data Output. The data output is supplied to this pin as a 16-bit serial word.
21	DIN	Serial Data Input. The data to be written is applied to this pin in serial form (16-bit word). This pin can act as an input pin or as a I/O pin depending on the serial interface mode the part is in (see Table X).
22	CLKIN	Master Clock Signal for the device (4 MHz for AD7853, 1.8 MHz for AD7853L). Sets the conversion and calibration times.
23	SCLK	Serial Port Clock. Logic input/output. The SCLK pin is configured as an input or output, dependent on the type of serial data transmission (self-clocking or external-clocking) that has been selected by the SM1 and SM2 pins. The SCLK idles high or low depending on the state of the POLARITY pin.
24	SYNC	This pin can be an input level triggered active low (similar to a chip select in one case and to a frame sync in the other) or an output (similar to a frame sync) pin depending on SM1, SM2 (see Table X).

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#### **TERMINOLOGY**

### **Integral Nonlinearity**

This is the maximum deviation from a straight line passing through the endpoints of the ADC transfer function. The endpoints of the transfer function are zero scale, a point 1/2 LSB below the first code transition, and full scale, a point 1/2 LSB above the last code transition.

### **Differential Nonlinearity**

This is the difference between the measured and the ideal 1 LSB change between any two adjacent codes in the ADC.

### **Total Unadjusted Error**

This is the deviation of the actual code from the ideal code taking all errors into account (*Gain*, *Offset*, *Integral Nonlinearity*, and other errors) at any point along the transfer function.

### **Unipolar Offset Error**

This is the deviation of the first code transition (00...000 to 00...001) from the ideal AIN(+) voltage (AIN(-) + 1/2 LSB) when operating in the unipolar mode.

### Positive Full-Scale Error

This applies to the unipolar and bipolar modes and is the deviation of the last code transition from the ideal AIN(+) voltage  $(AIN(-) + Full\ Scale - 1.5\ LSB)$  after the offset error has been adjusted out.

### **Negative Full-Scale Error**

This applies to the bipolar mode only and is the deviation of the first code transition  $(10 \dots 000 \text{ to } 10 \dots 001)$  from the ideal AIN(+) voltage  $(\text{AIN}(-) - \text{V}_{\text{REF}}/2 + 0.5 \text{ LSB})$ .

### **Bipolar Zero Error**

This is the deviation of the midscale transition (all 1s to all 0s) from the ideal AIN(+) voltage (AIN(-) – 1/2 LSB).

### Track/Hold Acquisition Time

The track/hold amplifier returns into track mode and the end of conversion. Track/Hold acquisition time is the time required for the output of the track/hold amplifier to reach its final value, within  $\pm 1/2$  LSB, after the end of conversion.

### Signal to (Noise + Distortion) Ratio

This is the measured ratio of signal to (noise + distortion) at the output of the A/D converter. The signal is the rms amplitude of the fundamental. Noise is the sum of all nonfundamental signals up to half the sampling frequency ( $f_S/2$ ), excluding dc. The ratio is dependent on the number of quantization levels in the digitization process; the more levels, the smaller the quantization noise. The theoretical signal to (noise + distortion) ratio for an ideal N-bit converter with a sine wave input is given by:

Signal to (Noise + Distortion) = (6.02 N + 1.76) dB

Thus for a 12-bit converter, this is 74 dB.

### **Total Harmonic Distortion**

Total harmonic distortion (THD) is the ratio of the rms sum of harmonics to the fundamental. For the AD7853/AD7853L, it is defined as:

THD (dB) = 
$$20 \log \frac{\sqrt{(V_2^2 + V_3^2 + V_4^2 + V_5^2 + V_6^2)}}{V_1}$$

where  $V_1$  is the rms amplitude of the fundamental and  $V_2$ ,  $V_3$ ,  $V_4$ ,  $V_5$  and  $V_6$  are the rms amplitudes of the second through the sixth harmonics.

#### Peak Harmonic or Spurious Noise

Peak harmonic or spurious noise is defined as the ratio of the rms value of the next largest component in the ADC output spectrum (up to  $f_{\rm S}/2$  and excluding dc) to the rms value of the fundamental. Normally, the value of this specification is determined by the largest harmonic in the spectrum, but for parts where the harmonics are buried in the noise floor, it will be a noise peak.

### **Intermodulation Distortion**

With inputs consisting of sine waves at two frequencies, fa and fb, any active device with nonlinearities will create distortion products at sum and difference frequencies of  $mfa \pm nfb$  where m, n = 0, 1, 2, 3, etc. Intermodulation distortion terms are those for which neither m nor n are equal to zero. For example, the second order terms include (fa + fb) and (fa - fb), while the third order terms include (2fa + fb), (2fa - fb), (fa + 2fb) and (fa - 2fb).

Testing is performed using the CCIF standard where two input frequencies near the top end of the input bandwidth are used. In this case, the second order terms are usually distanced in frequency from the original sine waves while the third order terms are usually at a frequency close to the input frequencies. As a result, the second and third order terms are specified separately. The calculation of the intermodulation distortion is as per the THD specification where it is the ratio of the rms sum of the individual distortion products to the rms amplitude of the sum of the fundamentals expressed in dBs.

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#### **ON-CHIP REGISTERS**

The AD7853/AD7853L powers up with a set of default conditions, and the user need not ever write to the device. In this case the AD7853/AD7853L will operate as a Read-Only ADC. The AD7853/AD7853L still retains the flexibility for performing a full power-down, and a full self-calibration. Note that the DIN pin should be tied to DGND for operating the AD7853/AD7853L as a Read-Only ADC.

Extra features and flexibility such as performing different power-down options, different types of calibrations including system calibration, and software conversion start can be selected by writing to the part.

The AD7853/AD7853L contains a **Control register**, **ADC output data register**, **Status register**, **Test register** and **10 Calibration registers**. The control register is write-only, the ADC output data register and the status register are read-only, and the test and calibration registers are both read/write registers. The test register is used for testing the part and should not be written to.

## Addressing the On-Chip Registers Writing

A write operation to the AD7853/AD7853L consists of 16 bits. The two MSBs, ADDR0 and ADDR1, are decoded to determine which register is addressed, and the subsequent 14 bits of data are written to the addressed register. It is not until all 16 bits are written that the data is latched into the addressed register. Table I shows the decoding of the address bits, while Figure 4 shows the overall write register hierarchy.

ADDR1	ADDR0	Comment
0	0	This combination does not address any register so the subsequent 14 data bits are ignored.
0	1	This combination addresses the <b>TEST REGISTER</b> . The subsequent 14 data bits are written to the test register.
1	0	This combination addresses the <b>CALIBRATION REGISTERS</b> . The subsequent 14 data bits are written to the selected calibration register.
1	1	This combination addresses the <b>CONTROL REGISTER</b> . The subsequent 14 data bits are written to the control register.

Table I. Write Register Addressing

#### Reading

To read from the various registers the user must first write to Bits 6 and 7 in the Control Register, RDSLT0 and RDSLT1. These bits are decoded to determine which register is addressed during a read operation. Table II shows the decoding of the read address bits while Figure 5 shows the overall read register hierarchy. The power-up status of these bits is 00 so that the default read will be from the ADC output data register.

Once the read selection bits are set in the control register all subsequent read operations that follow will be from the selected register until the read selection bits are changed in the control register.

RDSLT1	RDSLT0	Comment
0	0	All successive read operations will be from <b>ADC OUTPUT DATA REGISTER</b> . This is the power-up default setting. There will always be four leading zeros when reading from the ADC output data register.
0	1	All successive read operations will be from <b>TEST REGISTER</b> .
1	0	All successive read operations will be from <b>CALIBRATION REGISTERS</b> .
1	1	All successive read operations will be from <b>STATUS REGISTER</b> .

Table II. Read Register Addressing

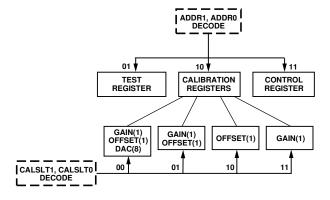


Figure 4. Write Register Hierarchy/Address Decoding

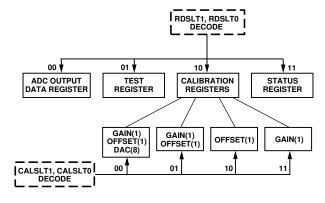


Figure 5. Read Register Hierarchy/Address Decoding

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### **CONTROL REGISTER**

The arrangement of the control register is shown below. The control register is a write only register and contains 14 bits of data. The control register is selected by putting two 1s in ADDR1 and ADDR0. The function of the bits in the control register are described below. The power-up status of all bits is 0.

### **MSB**

ZERO	ZERO	ZERO	ZERO	PMGT1	PMGT0	RDSLT1
RDSLT0	$2/\overline{3}$ MODE	CONVST	CALMD	CALSLT1	CALSLT0	STCAL

**LSB** 

### **Control Register Bit Function Descriptions**

Bit	Mnemonic	Comment
13 12 11 10	ZERO ZERO ZERO ZERO	These four bits must be set to 0 when writing to the control register.
9 8	PMGT1 PMGT0	Power Management Bits. These two bits are used with the SLEEP pin for putting the part into various power-down modes (See Power-Down section for more details).
7 6	RDSLT1 RDSLT0	These two bits determine which register is addressed for the read operations. See Table II.
5	2/3 MODE	Interface Mode Select Bit. With this bit set to 0, Interface Mode 2 is enabled. With this bit set to 1, Interface Mode 1 is enabled where DIN is used as an output as well as an input. This bit is set to 0 by default after every read cycle; thus when using Interface Mode 1, this bit needs to be set to 1 in every write cycle.
4	CONVST	Conversion Start Bit. A logic one in this bit position starts a single conversion, and this bit is automatically reset to 0 at the end of conversion. This bit may also used in conjunction with system calibration (see Calibration Section on page 21).
3	CALMD	Calibration Mode Bit. A 0 here selects self-calibration and a 1 selects a system calibration (see Table III).
2 1 0	CALSLT1 CALSLT0 STCAL	Calibration Selection Bits and Start Calibration Bit. These bits have two functions.  With the STCAL bit set to 1, the CALSLT1 and CALSLT0 bits determine the type of calibration performed by the part (see Table III). The STCAL bit is automatically reset to 0 at the end of calibration. With the STCAL bit set to 0, the CALSLT1 and CALSLT0 bits are decoded to address the calibration register for read/write of calibration coefficients (see section on the calibration registers for more details).

Table III. Calibration Selection

CALMD	CALSLT1	CALSLT0	Calibration Type
0	0	0	A <b>full internal calibration</b> is initiated where the internal DAC is calibrated followed by the internal gain error and finally the internal offset error is calibrated out. This is the default setting.
0	0	1	Here the <b>internal gain error</b> is calibrated out followed by the <b>internal offset error</b> calibrated out.
0	1	0	This calibrates out the <b>internal offset error</b> only.
0	1	1	This calibrates out the <b>internal gain error</b> only.
1	0	0	A <b>full system calibration</b> is initiated here where first the internal DAC is calibrated, followed by the system gain error, and finally the system offset error is calibrated out.
1	0	1	Here the <b>system gain error</b> is calibrated out followed by the <b>system offset error</b> .
1	1	0	This calibrates out the <b>system offset error</b> only.
1	1	1	This calibrates out the <b>system gain error</b> only.

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### **STATUS REGISTER**

The arrangement of the status register is shown below. The status register is a read-only register and contains 16 bits of data. The status register is selected by first writing to the control register and putting two 1s in RDSLT1 and RDSLT0. The function of the bits in the status register are described below. The power-up status of all bits is 0.

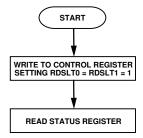


Figure 6. Flowchart for Reading the Status Register

### **MSB**

ZERO	BUSY	ZERO	ZERO	ZERO	ZERO	PMGT1	PMGT0
RDSLT1	RDSLT0	$2/\overline{3}$ MODE	X	CALMD	CALSLT1	CALSLT0	STCAL

LSB

### **Status Register Bit Function Descriptions**

Bit	Mnemonic	Comment	
15	ZERO	This bit is always 0.	
14	BUSY	Conversion/Calibration Busy Bit. When this bit is 1, it indicates that there is a conversion or calibration in progress. When this bit is 0, no conversion or calibration is in progress.	
13 12 11 10	ZERO ZERO ZERO ZERO	These four bits are always 0.	
9 8	PMGT1 PMGT0	Power Management Bits. These bits, along with the SLEEP pin, will indicate whether or not the part is in a power-down mode. See Table VI in Power-Down Section for description.	
7 6	RDSLT1 RDSLT0	Both of these bits are always 1, indicating it is the status register that is being read. See Table II.	
5	$2/\overline{3}$ MODE	Interface Mode Select Bit. With this bit at 0, the device is in Interface Mode 2. With this bit at 1, the device is in Interface Mode 1. This bit is reset to 0 after every read cycle.	
4	X	Don't care bit.	
3	CALMD	Calibration Mode Bit. A 0 in this bit indicates a self-calibration is selected; a 1 in this bit indicates a system calibration is selected (see Table III).	
2 1 0	CALSLT1 CALSLT0 STCAL	Calibration Selection Bits and Start Calibration Bit. The STCAL bit is read as a 1 if a calibration is in progress and as a 0 if no calibration is in progress. The CALSLT1 and CALSLT0 bits indicate which of the calibration registers are addressed for reading and writing (see section on the Calibration Registers for more details).	

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#### **CALIBRATION REGISTERS**

The AD7853/AD7853L has ten calibration registers in all, eight for the DAC, one for the offset and one for gain. Data can be written to or read from all ten calibration registers. In self- and system calibration the part automatically modifies the calibration registers; only if the user needs to modify the calibration registers should an attempt be made to read from and write to the calibration registers.

### Addressing the Calibration Registers

The calibration selection bits in the control register CALSLT1 and CALSLT0 determine which of the calibration registers are addressed (See Table IV). The addressing applies to both the read and write operations for the calibration registers. The user should not attempt to read from and write to the calibration registers at the same time.

Table IV. Calibration Register Addressing

CALSLT1	CALSLT0	Comment	
0	0	This combination addresses the Gain (1), Offset (1) and DAC Registers (8). Ten registers in total.	
0	1	This combination addresses the Gain (1) and Offset (1) Registers. Two registers in total.	
1	0	This combination addresses the <b>Offset Register</b> . One register in total.	
1	1	This combination addresses the Gain Register. One register in total.	

### Writing to/Reading from the Calibration Registers

For writing to the calibration registers a write to the control register is required to set the CALSLT0 and CALSLT1 bits. For reading from the calibration registers a write to the control register is required to set the CALSLT0 and CALSLT1 bits, but also to set the RDSLT1 and RDSLT0 bits to 10 (this addresses the calibration registers for reading). The calibration register pointer is reset on writing to the control register setting the CALSLT1 and CALSLT0 bits, or upon completion of all the calibration register write/read operations. When reset it points to the first calibration register in the selected write/read sequence. The calibration register pointer will point to the gain calibration register upon reset in all but one case, this case being where the offset calibration register is selected on its own (CALSLT1 = 1, CALSLT0 = 0). Where more than one calibration register is being accessed, the calibration register pointer will be automatically incremented after each calibration register write/read operation. The order in which the ten calibration registers are arranged is shown in Figure 7. The user may abort at any time before all the calibration register write/read operations are completed, and the next control register write operation will reset the calibration register pointer. The flowchart in Figure 8 shows the sequence for writing to the calibration registers and Figure 9 for reading.

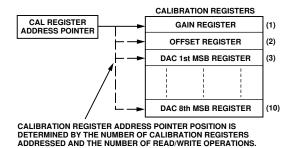


Figure 7. Calibration Register Arrangement

When reading from the calibration registers there will always be two leading zeros for each of the registers. When operating in serial Interface Mode 1, the read operations to the calibration registers cannot be aborted. The full number of read operations must be completed (see section on serial Interface Mode 1 timing for more detail).

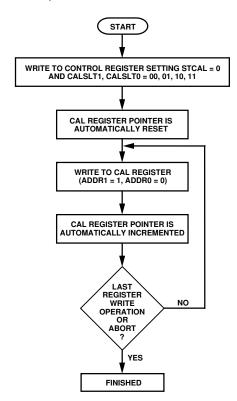


Figure 8. Flowchart for Writing to the Calibration Registers

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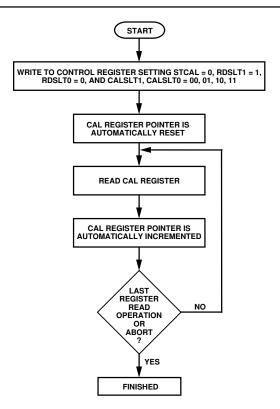


Figure 9. Flowchart for Reading from the Calibration Registers

### Adjusting the Offset Calibration Register

The offset calibration register contains 16 bits, two leading zeros and 14 data bits. By changing the contents of the offset register, different amounts of offset on the analog input signal can be compensated for. Increasing the number in the offset calibration register compensates for negative offset on the analog input signal, and decreasing the number in the offset calibration register compensates for positive offset on the analog input signal. The default value of the offset calibration register is 0010 0000 0000 0000 approximately. This is not an exact value, but the value in the offset register should be close to this value. Each of the 14 data bits in the offset register is binary weighted; the MSB has a weighting of 5% of the reference voltage, the MSB-1 has a weighting of 2.5%, the MSB-2 has a weighting of 1.25%, and so on down to the LSB, which has a weighting of 0.0006%.

This gives a resolution of  $\pm 0.0006\%$  of  $V_{REF}$  approximately. More accurately the resolution is  $\pm (0.05 \times V_{REF})/2^{13}$  volts =  $\pm 0.015$  mV, with a 2.5 V reference. The maximum offset that can be compensated for is  $\pm 5\%$  of the reference voltage, which equates to  $\pm 125$  mV with a 2.5 V reference and  $\pm 250$  mV with a 5 V reference.

- Q. If a +20 mV offset is present in the analog input signal and the reference voltage is 2.5 V, what code needs to be written to the offset register to compensate for the offset?
- A. 2.5 V reference implies that the resolution in the offset register is  $5\% \times 2.5 \text{ V}/2^{13} = 0.015 \text{ mV}$ . +20 mV/0.015 mV = 1310.72; rounding to the nearest number gives 1311. In binary terms this is 0101 0001 1111, therefore decrease the offset register by 0101 0001 1111.

This method of compensating for offset in the analog input signal allows for fine tuning the offset compensation. If the offset on the analog input signal is known, there will be no need to apply the offset voltage to the analog input pins and do a system calibration. The offset compensation can take place in software.

#### Adjusting the Gain Calibration Register

The gain calibration register contains 16 bits, two leading 0s and 14 data bits. The data bits are binary weighted as in the offset calibration register. The gain register value is effectively multiplied by the analog input to scale the conversion result over the full range. Increasing the gain register compensates for a smaller analog input range and decreasing the gain register compensates for a larger input range. The maximum analog input range that the gain register can compensate for is 1.025 times the reference voltage, and the minimum input range is 0.975 times the reference voltage.

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### **CIRCUIT INFORMATION**

The AD7853/AD7853L is a fast, 12-bit single supply A/D converter. The part requires an external 4 MHz/1.8 MHz master clock (CLKIN), two  $C_{REF}$  capacitors, a  $\overline{CONVST}$  signal to start conversion and power supply decoupling capacitors. The part provides the user with track/hold, on-chip reference, calibration features, A/D converter and serial interface logic functions on a single chip. The A/D converter section of the AD7853/AD7853L consists of a conventional successive-approximation converter based around a capacitor DAC. The AD7853/AD7853L accepts an analog input range of 0 to +V\_DD where the reference can be tied to  $V_{\rm DD}$ . The reference input to the part is buffered on-chip.

A major advantage of the AD7853/AD7853L is that a conversion can be initiated in software as well as applying a signal to the  $\overline{\text{CONVST}}$  pin. Another innovative feature of the AD7853/AD7853L is self-calibration on power-up, which is initiated having a capacitor from the  $\overline{\text{CAL}}$  pin to AGND, to give superior dc accuracy (See Automatic Calibration on Power-Up section). The part is available in a 24-lead SSOP package, which offers the user considerable space-saving advantages over alternative solutions. The AD7853L version typically consumes only 5.5 mW, making it ideal for battery-powered applications.

#### **CONVERTER DETAILS**

The master clock for the part must be applied to the CLKIN pin. Conversion is initiated on the AD7853/AD7853L by pulsing the CONVST input or by writing to the control register and setting the CONVST bit to 1. On the rising edge of CONVST (or at the end of the control register write operation), the onchip track/hold goes from track to hold mode. The falling edge of the CLKIN signal which follows the rising edge of the edge of CONVST signal initiates the conversion, provided the rising

edge of CONVST occurs at least 10 ns typically before this CLKIN edge. The conversion cycle will take 16.5 CLKIN periods from this CLKIN falling edge. If the 10 ns setup time is not met, the conversion will take 17.5 CLKIN periods. The maximum specified conversion time is 4.6 µs for the AD7853 (18  $t_{CLKIN}$ , CLKIN = 4 MHz) and 10  $\mu$ s for the AD7853L (18  $t_{CLKIN}$ , CLKIN = 1.8 MHz). When a conversion is completed, the BUSY output goes low, and then the result of the conversion can be read by accessing the data through the serial interface. To obtain optimum performance from the part, the read operation should not occur during the conversion or 400 ns prior to the next CONVST rising edge. However, the maximum throughput rates are achieved by reading/writing during conversion, and reading/writing during conversion is likely to degrade the Signal to (Noise + Distortion) by only 0.5 dBs. The AD7853 can operate at throughput rates up to 200 kHz, 100 kHz for the AD7853L. For the AD7853/AD7853L a conversion takes 18 CLKIN periods, 2 CLKIN periods are needed for the acquisition time giving a full cycle time of 5 µs (= 200 kHz, CLKIN = 4 MHz). For the AD7853L 100 kHz throughput can be obtained as follows: the CLKIN and CONVST signals are arranged to give a conversion time of 16.5 CLKIN periods as described above, 1.5 CLKIN periods are allowed for the acquisition time. This gives a full cycle time of 10 µs (= 100 kHz, CLKIN = 1.8 MHz). When using the software conversion start for maximum throughput, the user must ensure the control register write operation extends beyond the falling edge of BUSY. The falling edge of BUSY resets the CONVST bit to 0 and allows it to be reprogrammed to 1 to start the next conversion.

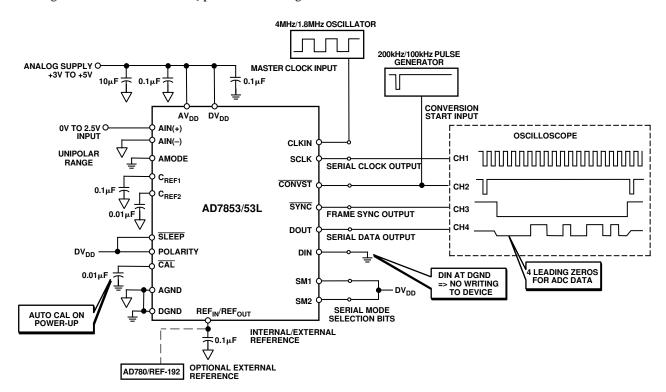


Figure 10. Typical Circuit

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### TYPICAL CONNECTION DIAGRAM

Figure 10 shows a typical connection diagram for the AD7853/ AD7853L. The DIN line is tied to DGND so that no data is written to the part. The AGND and the DGND pins are connected together at the device for good noise suppression. The  $\overline{CAL}$  pin has a 0.01  $\mu F$  capacitor to enable an automatic self-calibration on power-up. The SCLK and  $\overline{SYNC}$  are configured as outputs by having SM1 and SM2 at DVDD. The conversion result is output in a 16-bit word with four leading zeros followed by the MSB of the 12-bit result. Note that after the AVDD and DVDD power-up, the part will require approximately 150 ms for the internal reference to settle and for the automatic calibration on power-up to be completed.

For applications where power consumption is a major concern, the SLEEP pin can be connected to DGND. See Power-Down section for more detail on low power applications.

### **ANALOG INPUT**

The equivalent circuit of the analog input section is shown in Figure 11. During the acquisition interval the switches are both in the track position and the AIN(+) charges the 20 pF capacitor through the 125  $\Omega$  resistance. On the rising edge of  $\overline{\text{CONVST}}$ switches SW1 and SW2 go into the hold position retaining charge on the 20 pF capacitor as a sample of the signal on AIN(+). The AIN(-) is connected to the 20 pF capacitor, and this unbalances the voltage at Node A at the input of the comparator. The capacitor DAC adjusts during the remainder of the conversion cycle to restore the voltage at Node A to the correct value. This action transfers a charge, representing the analog input signal, to the capacitor DAC which in turn forms a digital representation of the analog input signal. The voltage on the AIN(-) pin directly influences the charge transferred to the capacitor DAC at the hold instant. If this voltage changes during the conversion period, the DAC representation of the analog input voltage will be altered. Therefore it is most important that the voltage on the AIN(-) pin remains constant during the conversion period. Furthermore, it is recommended that the AIN(-) pin is always connected to AGND or to a fixed dc voltage.

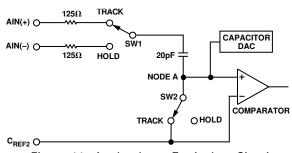


Figure 11. Analog Input Equivalent Circuit

### **Acquisition Time**

The track and hold amplifier enters its tracking mode on the falling edge of the BUSY signal. The time required for the track and hold amplifier to acquire an input signal will depend on how quickly the 20 pF input capacitance is charged. The acquisition time is calculated using the formula:

$$t_{ACO} = 9 \times (R_{IN} + 125 \Omega) \times 20 pF$$

where  $R_{IN}$  is the source impedance of the input signal, and 125  $\Omega$ , 20 pF is the input R, C.

### **DC/AC Applications**

For dc applications high source impedances are acceptable, provided there is enough acquisition time between conversions to charge the 20 pF capacitor. The acquisition time can be calculated from the above formula for different source impedances. For example with  $R_{\rm IN}$  = 5 k $\Omega$ , the required acquisition time will be 922 ns.

For ac applications, removing high frequency components from the analog input signal is recommended by use of an RC low-pass filter on the AIN(+) pin, as shown in Figure 13. In applications where harmonic distortion and signal to noise ratio are critical, the analog input should be driven from a low impedance source. Large source impedances will significantly affect the ac performance of the ADC. This may necessitate the use of an input buffer amplifier. The choice of the op amp will be a function of the particular application.

When no amplifier is used to drive the analog input the source impedance should be limited to low values. The maximum source impedance will depend on the amount of total harmonic distortion (THD) that can be tolerated. The THD will increase as the source impedance increases and performance will degrade. Figure 12 shows a graph of the Total Harmonic Distortion vs. analog input signal frequency for different source impedances. With the setup as in Figure 13, the THD is at the –90 dB level. With a source impedance of 1 k $\Omega$  and no capacitor on the AIN(+) pin, the THD increases with frequency.

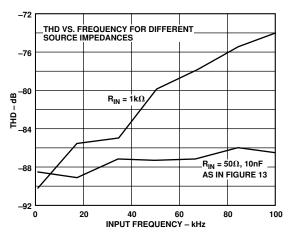


Figure 12. THD vs. Analog Input Frequency

In a single supply application (both 3 V and 5 V), the V+ and V– of the op amp can be taken directly from the supplies to the AD7853/AD7853L which eliminates the need for extra external power supplies. When operating with rail-to-rail inputs and outputs at frequencies greater than 10 kHz, care must be taken in selecting the particular op amp for the application. In particular, for single supply applications the input amplifiers should be connected in a gain of –1 arrangement to get the optimum performance. Figure 13 shows the arrangement for a single supply application with a 50  $\Omega$  and 10 nF low-pass filter (cutoff frequency 320 kHz) on the AIN(+) pin. Note that the 10 nF is a capacitor with good linearity to ensure good ac performance. Recommended single supply op amps are the AD820 and the AD820-3 V.

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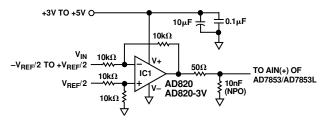


Figure 13. Analog Input Buffering

### **Input Ranges**

The analog input range for the AD7853/AD7853L is 0 V to  $V_{REF}$  in both the unipolar and bipolar ranges.

The only difference between the unipolar range and the bipolar range is that in the bipolar range the AIN(-) has to be biased up to  $+V_{REF}/2$  and the output coding is twos complement (See Table V and Figures 14 and 15). The unipolar or bipolar mode is selected by the AMODE pin (0 for the unipolar range and 1 for the bipolar range).

Table V. Analog Input Connections

Analog Input	Input Co	nnections	Connection	AMODE
Range	AIN(+)	AIN(-)	Diagram	
$0 \text{ V to V}_{\text{REF}}^{1}$	$egin{array}{c} V_{IN} \ V_{IN} \end{array}$	AGND	Figure 14	DGND
$\pm \text{V}_{\text{REF}}/2^{2}$		V <sub>REF</sub> /2	Figure 15	DV <sub>DD</sub>

NOTES

<sup>1</sup>Output code format is straight binary.

<sup>2</sup>Range is ±V<sub>REF</sub>/2 biased about V<sub>REF</sub>/2. Output code format is twos complement.

Note that the AIN(–) pin on the AD7853/AD7853L can be biased up above AGND in the unipolar mode also, if required. The advantage of biasing the lower end of the analog input range away from AGND is that the user does not have to have the analog input swing all the way down to AGND. This has the advantage in true single supply applications that the input amplifier does not have to swing all the way down to AGND. The upper end of the analog input range is shifted up by the same amount. Care must be taken so that the bias applied does not shift the upper end of the analog input above the  $AV_{\rm DD}$  supply. In the case where the reference is the supply,  $AV_{\rm DD}$ , the AIN(–) must be tied to AGND in unipolar mode.

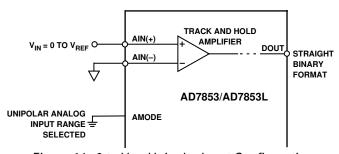


Figure 14. 0 to  $V_{REF}$  Unipolar Input Configuration

### **Transfer Functions**

For the unipolar range the designed code transitions occur midway between successive integer LSB values (i.e., 1/2 LSB, 3/2 LSBs, 5/2 LSBs . . . FS -3/2 LSBs). The output coding is straight binary for the unipolar range with 1 LSB = FS/4096 = 3.3 V/4096 = 0.8 mV when  $V_{REF}$  = 3.3 V. The ideal input/output transfer characteristic for the unipolar range is shown in Figure 16.

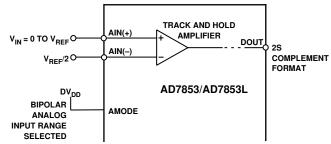


Figure 15.  $\pm V_{REF}/2$  about  $V_{REF}/2$  Bipolar Input Configuration

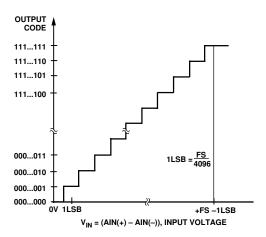


Figure 16. Unipolar Transfer Characteristic

Figure 15 shows the AD7853/AD7853L's  $\pm V_{REF}/2$  bipolar analog input configuration (where AIN(+) cannot go below 0 V so for the full bipolar range then the AIN(–) pin should be biased to  $\pm V_{REF}/2$ ). Once again the designed code transitions occur midway between successive integer LSB values. The output coding is twos complement with 1 LSB = 4096 = 3.3~V/4096 = 0.8~mV. The ideal input/output transfer characteristic is shown in Figure 17.

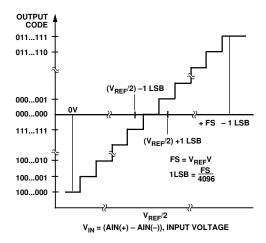


Figure 17. Bipolar Transfer Characteristic

### REFERENCE SECTION

For specified performance, it is recommended that when using an external reference this reference should be between 2.3 V and the analog supply  $AV_{\rm DD}$ . The connections for the relevant reference pins are shown in the typical connection diagrams. If the internal reference is being used, the  $REF_{\rm IN}/REF_{\rm OUT}$  pin should have a 100 nF capacitor connected to AGND very close to the  $REF_{\rm IN}/REF_{\rm OUT}$  pin. These connections are shown in Figure 18.

If the internal reference is required for use external to the ADC, it should be buffered at the REF<sub>IN</sub>/REF<sub>OUT</sub> pin and a 100 nF connected from this pin to AGND. The typical noise performance for the internal reference, with 5 V supplies is 150 nV/ $\sqrt{\rm Hz}$  @ 1 kHz and dc noise is 100  $\mu V$  p-p.

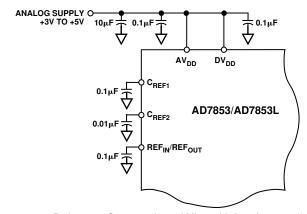


Figure 18. Relevant Connections When Using Internal Reference

The other option is that the REF<sub>IN</sub>/REF<sub>OUT</sub> pin be overdriven by connecting it to an external reference. This is possible due to the series resistance from the REF<sub>IN</sub>/REF<sub>OUT</sub> pin to the internal reference. This external reference can have a range that includes AV<sub>DD</sub>. When using AV<sub>DD</sub> as the reference source, the 100 nF capacitor from the REF<sub>IN</sub>/REF<sub>OUT</sub> pin to AGND should be as close as possible to the REF<sub>IN</sub>/REF<sub>OUT</sub> pin, and also the C<sub>REF1</sub> pin should be connected to AV<sub>DD</sub> to keep this pin at the same level as the reference. The connections for this arrangement are shown in Figure 19. When using AV<sub>DD</sub> it may be necessary to add a resistor in series with the AV<sub>DD</sub> supply. This will have the effect of filtering the noise associated with the AV<sub>DD</sub> supply.

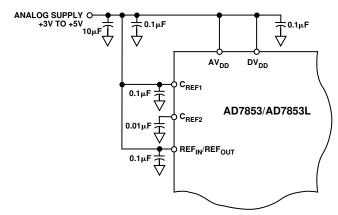


Figure 19. Relevant Connections When Using  $AV_{DD}$  as the Reference

#### PERFORMANCE CURVES

Figure 20 shows a typical FFT plot for the AD7853 at 200 kHz sample rate and 10 kHz input frequency.

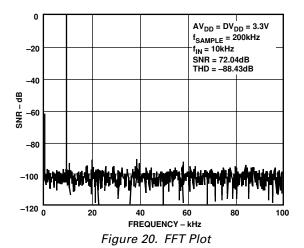


Figure 21 shows the SNR versus Frequency for different supplies and different external references.

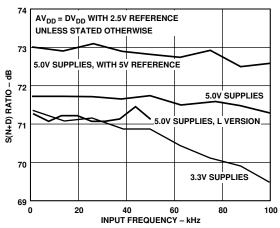


Figure 21. SNR vs. Frequency

Figure 22 shows the Power Supply Rejection Ratio versus Frequency for the part. The Power Supply Rejection Ratio is defined as the ratio of the power in ADC output at frequency f to the power of a full-scale sine wave.

$$PSRR (dB) = 10 log (Pf/Pfs)$$

Pf = Power at frequency f in ADC output, Pfs = power of a full-scale sine wave. Here a 100 mV peak-to-peak sine wave is coupled onto the AV<sub>DD</sub> supply while the digital supply is left unaltered. Both the 3.3 V and 5.0 V supply performances are shown.

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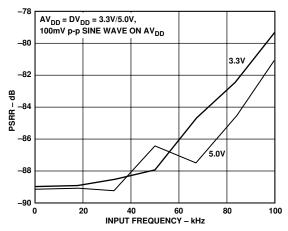


Figure 22. PSRR vs. Frequency

### **POWER-DOWN OPTIONS**

The AD7853 provides flexible power management to allow the user to achieve the best power performance for a given throughput rate. The power management options are selected by programming the power management bits, PMGT1 and PMGT0, in the control register and by use of the  $\overline{\rm SLEEP}$  pin. Table VI summarizes the power-down options that are available and how they can be selected by using either software, hardware or a combination of both. The AD7853 can be fully or partially powered down. When fully powered down, all the on-chip circuitry is powered down and  $\rm I_{DD}$  is 1  $\rm \mu A$  typ. If a partial power-down is selected, then all the on-chip circuitry except the reference

is powered down and  $I_{DD}$  is 400  $\mu A$  typ. The choice of full or partial power-down does not give any significant improvement in throughput with a power-down between conversions. This is discussed in the next section–Power-Up Times. However, a partial power-down does allow the on-chip reference to be used externally even though the rest of the AD7853 circuitry is powered down. It also allows the AD7853 to be powered up faster after a long power-down period when using the on-chip reference (See Power-Up Times–Using On-Chip Reference).

When using the SLEEP pin, the power management bits PMGT1 and PMGT0 should be set to zero (default status on power-up). Bringing the SLEEP pin logic high ensures normal operation, and the part does not power down at any stage. This may be necessary if the part is being used at high throughput rates when it is not possible to power down between conversions. If the user wishes to power down between conversions at lower throughput rates (i.e. <100 kSPS for the AD7853) to achieve better power performances, then the SLEEP pin should be tied logic low.

If the power-down options are to be selected in software only, then the SLEEP pin should be tied logic high. By setting the power management bits PMGT1 and PMGT0 as shown in Table VI, a Full Power-Down, Full Power-Up, Full Power-Down Between Conversions, and a Partial Power-Down Between Conversions can be selected.

A typical connection diagram for a low power application is shown in Figure 23 (AD7853L is the low power version of the AD7853).

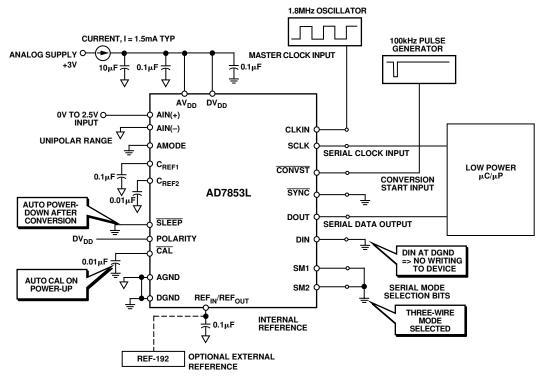


Figure 23. Typical Low Power Circuit

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Table VI. Power Management Options

PMGT1 Bit	PMGT0 Bit	SLEEP Pin	Comment
0	0	0	Full Power-Down if Not Calibrating or Converting (Default Condition After Power-On)
0	0	1	Normal Operation
0	1	X	Normal Operation
			(Independent of the SLEEP Pin)
1	0	X	Full Power-Down
1 .	1	X	Partial Power-Down if Not Converting

### **POWER-UP TIMES**

### Using an External Reference

When the AD7853 is powered up, the part is powered up from one of two conditions. First, when the power supplies are initially powered up and, secondly, when the part is powered up from either a hardware or software power-down (see last section).

When  $AV_{DD}$  and  $DV_{DD}$  are powered up, the AD7853 should be left idle for approximately 32 ms (4 MHz CLK) to allow for the autocalibration if a 10 nF cap is placed on the  $\overline{CAL}$  pin, (see Calibration section). During power-up the functionality of the  $\overline{SLEEP}$  pin is disabled, i.e., the part will not power down until the end of the calibration if  $\overline{SLEEP}$  is tied logic low. The autocalibration on power-up can be disabled if the  $\overline{CAL}$  pin is tied to a logic high. If the autocalibration is disabled, then the user must take into account the time required by the AD7853 to power-up before a self-calibration is carried out. This power-up time is the time taken for the AD7853 to power up when power is first applied (300  $\mu$ s) typ) or the time it takes the external reference to settle to the 12-bit level-whichever is the longer.

The AD7853 powers up from a full hardware or software power-down in 5 µs typ. This limits the throughput which the part is capable of to 104 kSPS for the AD7853 operating with a 4 MHz CLK and 66 kSPS for the AD7853L with a 1.8 MHz CLK when powering down between conversions. Figure 24 shows how power-down between conversions is implemented using the CONVST pin. The user first selects the power-down between conversions option by using the SLEEP pin and the power management bits, PMGT1 and PMGT0, in the control register, (see last section). In this mode the AD7853 automatically enters a full power-down at the end of a conversion, i.e., when BUSY goes low. The falling edge of the next CONVST pulse causes the part to power up. Assuming the external reference is left powered up, the AD7853 should be ready for normal operation 5 µs after this falling edge. The rising edge of CONVST initiates a conversion so the CONVST pulse should be at least 5 μs wide. The part automatically powers down on completion of the conversion.

NOTE: Where the software CONVST is used or automatic full power-down, the part must be powered up in software with an extra write setting PMGT1 = 0 and PMGT0 = 1 before a conversion is initiated in the next write. Automatic partial power-down after a calibration is not possible; the part must be powered down manually. If software calibrations are to be used when operating in the partial power-down mode, then three separate

writes are required. The first initiates the type of calibration required, the second write powers the part down into partial power-down mode, while the third write powers the part up again before the next calibration command is issued.

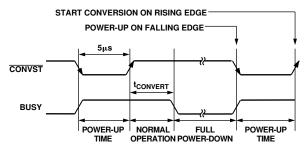


Figure 24. Power-Up Timing When Using CONVST Pin

### Using the Internal (On-Chip) Reference

As in the case of an external reference, the AD7853 can power-up from one of two conditions, power-up after the supplies are connected or power-up from hardware/software power-down. When using the on-chip reference and powering up when  $AV_{\rm DD}$  and  $DV_{\rm DD}$  are first connected, it is recommended that the power-up calibration mode be disabled as explained above. When using the on-chip reference, the power-up time is effectively the time it takes to charge up the external capacitor on the  $REF_{\rm IN}/REF_{\rm OUT}$  pin. This time is given by the equation:

$$t_{IIP} = 9 \times R \times C$$

where  $R \cong 150 \text{ k}\Omega$  and C = external capacitor.

The recommended value of the external capacitor is 100 nF; this gives a power-up time of approximately 135 ms before a calibration is initiated and normal operation should commence.

When C<sub>REF</sub> is fully charged, the power-up time from a hardware or software power-down reduces to 5 µs. This is because an internal switch opens to provide a high impedance discharge path for the reference capacitor during power-down—see Figure 23. An added advantage of the low charge leakage from the reference capacitor during power-down is that even though the reference is being powered down between conversions, the reference capacitor holds the reference voltage to within 0.5 LSBs with throughput rates of 100 samples/second and over with a full power-down between conversions. A high input impedance op amp like the AD707 should be used to buffer this reference capacitor if it is being used externally. Note, if the AD7853 is left in its power-down state for more than 100 ms, the charge on C<sub>REF</sub> will start to leak away and the power-up time will increase. If this long power-up time is a problem, the user can use a partial power-down for the last conversion so the reference remains powered up.

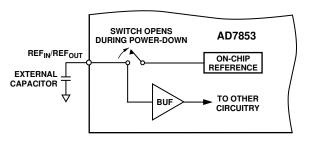


Figure 25. On-Chip Reference During Power-Down

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### POWER VS. THROUGHPUT RATE

The main advantage of a full power-down after a conversion is that it significantly reduces the power consumption of the part at lower throughput rates. When using this mode of operation, the AD7853 is only powered up for the duration of the conversion. If the power-up time of the AD7853 is taken to be 5 µs and it is assumed that the current during power-up is 4 mA typ, then power consumption as a function of throughput can easily be calculated. The AD7853 has a conversion time of 4.6 µs with a 4 MHz external clock. This means the AD7853 consumes 4 mA typ, (or 12 mW typ  $V_{DD}$  = 3 V) for 9.6  $\mu$ s in every conversion cycle if the device is powered down at the end of a conversion. If the throughput rate is 1 kSPS, the cycle time is 1000 us and the average power dissipated during each cycle is  $(9.6/1000) \times (12 \text{ mW}) = 115 \,\mu\text{W}$ . The graph, Figure 24, shows the power consumption of the AD7853 as a function of throughput. Table VII lists the power consumption for various throughput rates.

Table VII. Power Consumption vs. Throughput

Throughput Rate	Power
1 kSPS	115 μW
10 kSPS	1.15 mW

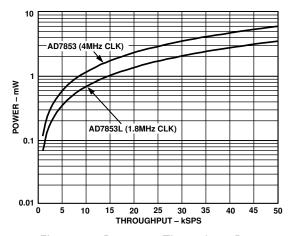


Figure 26. Power vs. Throughput Rate

### **CALIBRATION SECTION**

### **Calibration Overview**

The automatic calibration that is performed on power-up ensures that the calibration options covered in this section will not be required in a significant amount of applications. The user will not have to initiate a calibration unless the operating conditions change (CLKIN frequency, analog input mode, reference voltage, temperature, and supply voltages). The AD7853/AD7853L have a number of calibration features that may be required in some applications and there are a number of advantages in performing these different types of calibration. First, the internal errors in the ADC can be reduced significantly to give superior dc performance; and second, system offset and gain errors can be removed. This allows the user to remove reference errors (whether it be internal or external reference) and to make use of the full dynamic range of the AD7853/AD7853L by adjusting the analog input range of the part for a specific system.

There are two main calibration modes on the AD7853/AD7853L, self-calibration and system calibration. There are various options in both self-calibration and system calibration as outlined previously in Table III. All the calibration functions can be initiated by pulsing the  $\overline{CAL}$  pin or by writing to the control register and setting the STCAL bit to 1. The timing diagrams that follow involve using the  $\overline{CAL}$  pin.

The duration of each of the different types of calibrations is given in Table VIII for the AD7853 with a 4 MHz master clock. These calibration times are master clock dependent. Therefore the calibration times for the AD7853L (CLKIN = 1.8 MHz) will be larger than those quoted in Table VIII.

Table VIII. Calibration Times (AD7853 with 4 MHz CLKIN)

Type of Self- or System Calibration	Time
Full	31.25 ms
Gain + Offset	6.94 ms
Offset	3.47 ms
Gain	3.47 ms

### Automatic Calibration on Power-On

The CAL pin has a 0.15 µA pull-up current source connected to it internally to allow for an automatic full self-calibration on power-on. A full self-calibration will be initiated on power-on if a capacitor is connected from the  $\overline{CAL}$  pin to DGND. The internal current source connected to the  $\overline{CAL}$  pin charges up the external capacitor and the time required to charge the external capacitor will depend on the size of the capacitor itself. This time should be large enough to ensure that the internal reference is settled before the calibration is performed. A 33 nF capacitor is sufficient to ensure that the internal reference has settled (see Power-Up Times) before a calibration is initiated taking into account trigger level and current source variations on the CAL pin. However, if an external reference is being used, this reference must have stabilized before the automatic calibration is initiated (a larger capacitor on the CAL pin should be used if the external reference has not settled when the autocalibration is initiated). Once the capacitor on the  $\overline{CAL}$  pin has charged, the calibration will be performed which will take 32 ms (4 MHz CLKIN). Therefore the autocalibration should be complete before operating the part. After calibration, the part is accurate to the 12-bit level and the specifications quoted on the data sheet apply. There will be no need to perform another calibration unless the operating conditions change or unless a system calibration is required.

#### **Self-Calibration Description**

There are a four different calibration options within the self-calibration mode. There is a full self-calibration where the DAC, internal offset, and internal gain errors are calibrated out. Then, there is the (Gain + Offset) self-calibration which calibrates out the internal gain error and then the internal offset errors. The internal DAC is not calibrated here. Finally, there are the self-offset and self-gain calibrations which calibrate out the internal offset errors and the internal gain errors respectively.

The internal capacitor DAC is calibrated by trimming each of the capacitors in the DAC. It is the ratio of these capacitors to each other that is critical, and so the calibration algorithm ensures that this ratio is at a specific value by the end of the calibration routine. For the offset and gain there are two separate

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capacitors, one of which is trimmed when an offset or gain calibration is performed. Again it is the ratio of these capacitors to the capacitors in the DAC that is critical and the calibration algorithm ensures that this ratio is at a specified value for both the offset and gain calibrations.

In Bipolar Mode the midscale error is adjusted for an offset calibration and the positive full-scale error is adjusted for the gain calibration; in Unipolar Mode the zero-scale error is adjusted for an offset calibration and the positive full-scale error is adjusted for a gain calibration.

#### **Self-Calibration Timing**

The diagram of Figure 27 shows the timing for a full selfcalibration. Here the BUSY line stays high for the full length of the self-calibration. A self-calibration is initiated by bringing the CAL pin low (which initiates an internal reset) and then high again or by writing to the control register and setting the STCAL bit to 1 (note that if the part is in a power-down mode, the CAL pulsewidth must take account of the power-up time). The BUSY line is triggered high from the rising edge of  $\overline{CAL}$  (or the end of the write to the control register if calibration is initiated in software), and BUSY will go low when the full self-calibration is complete after a time  $t_{CAL}$  as shown in Figure 27.

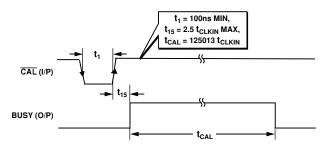


Figure 27. Timing Diagram for Full Self-Calibration

For the self-(gain + offset), self-offset and self-gain calibrations, the BUSY line will be triggered high by the rising edge of the <u>CAL</u> signal (or the end of the write to the control register if calibration is initiated in software) and will stay high for the full duration of the self-calibration. The length of time that the BUSY is high for will depend on the type of self-calibration that is initiated. Typical figures are given in Table IX. The timing diagrams for the other self-calibration options will be similar to that outlined in Figure 27.

### **System Calibration Description**

System calibration allows the user to take out system errors external to the AD7853/AD7853L as well as calibrate the errors of the AD7853/AD7853L itself. The maximum calibration range for the system offset errors is  $\pm 5\%$  of  $V_{REF}\,$  and for the system gain errors is  $\pm 2.5\%$  of  $V_{REF}$ . This means that the maximum allowable system offset voltage applied between the AIN(+) and AIN(-) pins for the calibration to adjust out this error is  $\pm 0.05 \times V_{REF}$  (i.e., the AIN(+) can be  $0.05 \times V_{REF}$  above AIN(-) or  $0.05 \times V_{REF}$  below AIN(-)). For the system gain error the maximum allowable system full-scale voltage, in unipolar mode, that can be applied between AIN(+) and AIN(-) for the calibration to adjust out this error is  $V_{REF} \pm 0.025 \times V_{REF}$  (i.e., the AIN(+) can be  $V_{REF}$  + 0.025 ×  $V_{REF}$  above AIN(-) or  $V_{REF}$  - $0.025 \times V_{REF}$  above AIN(-)). If the system offset or system gain

errors are outside the ranges mentioned, the system calibration algorithm will reduce the errors as much as the trim range allows. Figures 33 through 35 illustrate why a specific type of system calibration might be used. Figure 33 shows a system offset calibration (assuming a positive offset) where the analog input

range has been shifted upwards by the system offset after the system offset calibration is completed. A negative offset may also be accounted for by a system offset calibration.

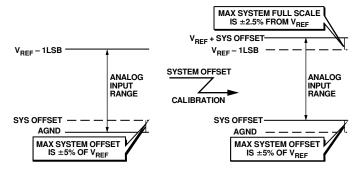


Figure 28. System Offset Calibration

Figure 29 shows a system gain calibration (assuming a system full scale greater than the reference voltage) where the analog input range has been increased after the system gain calibration is completed. A system full-scale voltage less than the reference voltage may also be accounted for a by a system gain calibration.

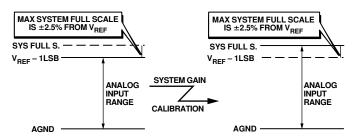


Figure 29. System Gain Calibration

Finally in Figure 30 both the system offset and gain are accounted for by the system offset followed by a system gain calibration. First the analog input range is shifted upwards by the positive system offset and then the analog input range is adjusted at the top end to account for the system full scale.

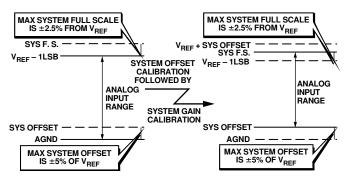


Figure 30. System (Gain + Offset) Calibration

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### System Gain and Offset Interaction

The inherent architecture of the AD7853/AD7853L leads to an interaction between the system offset and gain errors when a system calibration is performed. Therefore it is recommended to perform the cycle of a system offset calibration followed by a system gain calibration twice. Separate system offset and system gain calibrations reduce the offset and gain errors to at least the 12-bit level. By performing a system offset calibration first and a system gain calibration second, priority is given to reducing the gain error to zero before reducing the offset error to zero. If the system errors are small, a system offset calibration would be performed, followed by a system gain calibration. If the systems errors are large (close to the specified limits of the calibration range), this cycle would be repeated twice to ensure that the offset and gain errors were reduced to at least the 12-bit level. The advantage of doing separate system offset and system gain calibrations is that the user has more control over when the analog inputs need to be at the required levels, and the CONVST signal does not have to be used.

Alternatively, a system (gain + offset) calibration can be performed. It is recommended to perform three system (gain + offset) calibrations to reduce the offset and gain errors to the 12-bit level. For the system (gain + offset) calibration priority is given to reducing the offset error to zero before reducing the gain error to zero. Thus if the system errors are small then two system (gain + offset) calibrations will be sufficient. If the system errors are large (close to the specified limits of the calibration range), three system (gain + offset) calibrations may be required to reduced the offset and gain errors to at least the 12-bit level. There will never be any need to perform more than three system (offset + gain) calibrations.

In Bipolar Mode the midscale error is adjusted for an offset calibration and the positive full-scale error is adjusted for the gain calibration; in Unipolar Mode the zero-scale error is adjusted for an offset calibration and the positive full-scale error is adjusted for a gain calibration.

### **System Calibration Timing**

The calibration timing diagram in Figure 31 is for a full system calibration where the falling edge of  $\overline{CAL}$  initiates an internal reset before starting a calibration (note that if the part is in power-down mode the  $\overline{CAL}$  pulsewidth must take account of the power-up time). If a full system calibration is to be performed in software, it is easier to perform separate gain and offset calibrations so that the CONVST bit in the control register does not have to be programmed in the middle of the system calibration sequence. The rising edge of  $\overline{CAL}$  starts calibration of the internal DAC and causes the BUSY line to go high. If the control register is set for a full system calibration, the  $\overline{CONVST}$  must be used also. The full-scale system voltage should be applied to the analog input pins from the start of calibration. The BUSY line will go low once the DAC and system gain calibration are

complete. Next the system offset voltage is applied to the AIN pin for a minimum setup time ( $t_{SETUP}$ ) of 100 ns before the rising edge of the  $\overline{CONVST}$  and remain until the BUSY signal goes low. The rising edge of the  $\overline{CONVST}$  starts the system offset calibration section of the full system calibration and also causes the BUSY signal to go high. The BUSY signal will go low after a time  $t_{CAL2}$  when the calibration sequence is complete.

The timing for a system (gain + offset) calibration is very similar to that of Figure 31, the only difference being that the time  $t_{CAL1}$  will be replaced by a shorter time of the order of  $t_{CAL2}$  as the internal DAC will not be calibrated. The BUSY signal will signify when the gain calibration is finished and when the part is ready for the offset calibration.

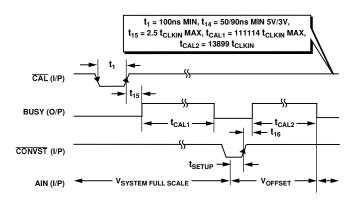


Figure 31. Timing Diagram for Full System Calibration

The timing diagram for a system offset or system gain calibration is shown in Figure 32. Here again the  $\overline{CAL}$  is pulsed and the rising edge of the  $\overline{CAL}$  initiates the calibration sequence (or the calibration can be initiated in software by writing to the control register). The rising edge of the  $\overline{CAL}$  causes the BUSY line to go high and it will stay high until the calibration sequence is finished. The analog input should be set at the correct level for a minimum setup time ( $t_{SETUP}$ ) of 100 ns before the rising edge of  $\overline{CAL}$  and stay at the correct level until the BUSY signal goes low.

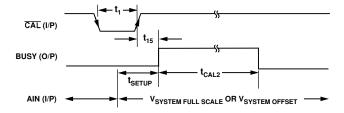


Figure 32. Timing Diagram for System Gain or System Offset Calibration

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### **SERIAL INTERFACE SUMMARY**

Table IX details the five interface modes and the serial clock edges from which the data is clocked out by the AD7853/AD7853L (DOUT Edge) and that the data is latched in on (DIN Edge). The logic level of the POLARITY pin is shown and it is clear that this reverses the edges.

In Interface Modes 4 and 5 the  $\overline{SYNC}$  always clocks out the first data bit and SCLK will clock out the subsequent bits.

In Interface Modes 1, 2, and 3 the  $\overline{SYNC}$  is gated with the SCLK and the POLARITY pin. Thus the  $\overline{SYNC}$  may clock out the MSB of data. Subsequent bits will be clocked out by the serial clock, SCLK. The conditions for the  $\overline{SYNC}$  clocking out the MSB of data is as follows:

With the POLARITY pin high the falling edge of SYNC will clock out the MSB if the serial clock is low when the SYNC goes low.

With the POLARITY pin low the falling edge of  $\overline{SYNC}$  will clock out the MSB if the serial clock is high when the  $\overline{SYNC}$  goes low.

Table IX. SCLK Active Edge for Different Interface Modes

Interface	POLARITY	DOUT	DIN
Mode	Pin	Edge	Edge
1, 2, 3	0	SCLK↑	SCLK↓
	1	SCLK↓	SCLK↑
4, 5	0 1	SCLK↓ SCLK↑	SCLK↑ SCLK↓

#### Resetting the Serial Interface

When writing to the part via the DIN line there is the possibility of writing data into the incorrect registers, such as the test register for instance, or writing the incorrect data and corrupting the serial interface. The  $\overline{SYNC}$  pin acts as a reset. Bringing the  $\overline{SYNC}$  pin high resets the internal shift register. The first data bit after the next  $\overline{SYNC}$  falling edge will now be the first bit of a new 16-bit transfer. It is also possible that the test register contents were altered when the interface was lost. Therefore, once the serial interface is reset, it may be necessary to write the 16-bit word 0100 0000 0000 0010 to restore the test register to its default value. Now the part and serial interface are completely reset. It is always useful to retain the ability to program the  $\overline{SYNC}$  line from a port of the  $\mu Controller/DSP$  to have the ability to reset the serial interface.

Table X summarizes the interface modes provided by the AD7853/AD7853L. It also outlines the various  $\mu P/\mu C$  to which the particular interface is suited.

The interface mode is determined by the serial mode selection pins SM1 and SM2. Interface Mode 2 is the default mode. Note that Interface Mode 1 and 2 have the same combination of SM1 and SM2. Interface Mode 1 may only be set by programming the control register (see section on control register). External

SCLK and SYNC signals (SYNC may be hardwired low) are required for Interfaces Modes 1, 2, and 3. In Interface Modes 4 and 5, the AD7853/AD7853L generates the SCLK and SYNC.

Some of the more popular  $\mu Processors$ ,  $\mu Controllers$ , and the DSP machines that the AD7853/AD7853L will interface to directly are mentioned here. This does not cover all  $\mu Cs$ ,  $\mu Ps$  and DSPs. The interface mode of the AD7853/AD7853L that is mentioned here for a specific  $\mu C$ ,  $\mu P$ , or DSP is only a guide and in most cases another interface mode may work just as well.

A more detailed timing description on each of the interface modes follows.

Table X. Interface Mode Description

SM1 Pin	SM2 Pin	μProcessor/ μController	Interface Mode
0	0	8XC51 8XL51 PIC17C42	1 (2-Wire) (DIN is an Input/ Output pin)
0	0	68HC11 68L11	2 (3-Wire, SPI/QSPI) (Default Mode)
0	1	68HC16 PIC16C64 ADSP-21xx DSP56000 DSP56001 DSP56002 DSP56L002 TMS320C30	3 (QSPI) (External Serial Clock, SCLK, and External Frame Sync, SYNC, are required)
1	0	68HC16	4 (DSP is Slave) (AD7853/AD7853L generates a noncontinuous [16 clocks] Serial Clock, SCLK, and the Frame Sync, SYNC)
1	1	ADSP-21xx DSP56000 DSP56001 DSP56002 DSP56L002 TMS320C20 TMS320C25 TMS320C30 TMS320C5x TMS320C5x	5 (DSP is Slave) (AD7853/AD7853L generates a continuous Serial Clock, SCLK, and the Frame Sync, SYNC)

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#### **DETAILED TIMING SECTION**

### Mode 1 (2-Wire 8051 Interface)

The read and writing takes place on the DIN line and the conversion is initiated by pulsing the  $\overline{\text{CONVST}}$  pin (note that in every write cycle the  $2/\overline{3}$  Mode bit must be set to 1). The conversion may be started by setting the CONVST bit in the control register to 1 instead of using the  $\overline{\text{CONVST}}$  line.

Below in Figure 33 and in Figure 34 are the timing diagrams for Interface Mode 1 in Table X where we are in the 2-wire interface mode. Here the DIN pin is used for both input and output as shown. The SYNC input is level triggered active low and can be pulsed (Figure 33) or can be constantly low (Figure 34).

In Figure 33 the part samples the input data on the rising edge of SCLK. After the 16th rising edge of SCLK the DIN is configured as an output. When the  $\overline{\text{SYNC}}$  is taken high the DIN is three-stated. Taking  $\overline{\text{SYNC}}$  low disables the three-state on the DIN pin and the first SCLK falling edge clocks out the first data bit. Once the 16 clocks have been provided the DIN pin will automatically revert back to an input after a time  $t_{14}$ . Note that a continuous SCLK shown by the dotted waveform in Figure 33

can be used provided that the  $\overline{SYNC}$  is low for only 16 clock pulses in each of the read and write cycles. The POLARITY pin may be used to change the SCLK edge which the data is sampled on and clocked out on.

In Figure 34 the SYNC line is tied low permanently and this results in a different timing arrangement. With SYNC tied low permanently the DIN pin will never be three-stated. The 16th rising edge of SCLK configures the DIN pin as an input or an output as shown in the diagram. Here no more than 16 SCLK pulses must occur for each of the read and write operations.

If reading from and writing to the calibration registers in this interface mode, all the selected calibration registers must be read from or written to. The read and write operations cannot be aborted. When reading from the calibration registers, the DIN pin will remain as an output for the full duration of all the calibration register read operations. When writing to the calibration registers, the DIN pin will remain as an input for the full duration of all the calibration register write operations.

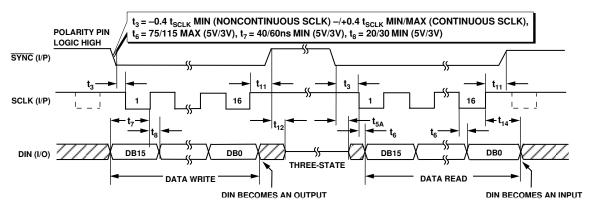


Figure 33. Timing Diagram for Read/Write Operation with DIN as an Input/Output (i.e., Interface Mode 1, SM1 = SM2 = 0)

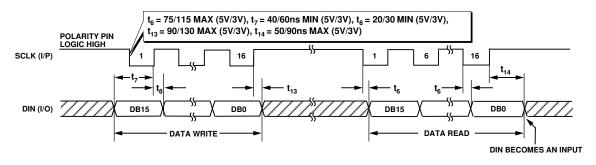


Figure 34. Timing Diagram for Read/Write Operation with DIN as an Input/Output and  $\overline{SYNC}$  Input Tied Low (i.e., Interface Mode 1, SM1 = SM2 = 0)

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# Mode 2 (3-Wire SPI/QSPI Interface Mode) This is the DEFAULT INTERFACE MODE.

In Figure 35 below we have the timing diagram for Interface Mode 2 which is the SPI/QSPI interface mode. Here the SYNC input is active low and may be pulsed or tied permanently low. If SYNC is permanently low 16 clock pulses must be applied to the SCLK pin for the part to operate correctly, and with a pulsed SYNC input a continuous SCLK may be applied provided SYNC is low for only 16 SCLK cycles. In Figure 30 the SYNC going low disables the three-state on the DOUT pin. The first falling edge of the SCLK after the SYNC going low clocks out the first leading zero on the DOUT pin. The DOUT pin is three-stated again a time  $t_{12}$  after the  $\overline{SYNC}$  goes high. With the DIN pin the data input has to be set up a time, t<sub>7</sub>, before the SCLK rising edge as the part samples the input data on the SCLK rising edge in this case. The POLARITY pin may be used to change the SCLK edge which the data is sampled on and clocked out on. If resetting the interface is required, the SYNC must be taken high and then low.

### Mode 3 (QSPI Interface Mode)

Figure 36 shows the timing diagram for Interface Mode 3. In this mode the DSP is the master and the part is the slave. Here the  $\overline{\text{SYNC}}$  input is edge triggered from high to low, and the 16 clock pulses are counted from this edge. Since the clock pulses are counted internally then the  $\overline{\text{SYNC}}$  signal does not have to go

high after the 16th SCLK rising edge as shown by the dotted  $\overline{\text{SYNC}}$  line in Figure 36. Thus a frame sync that gives a high pulse, of one SCLK cycle minimum duration, at the beginning of the read/write operation may be used. The rising edge of  $\overline{\text{SYNC}}$  enables the three-state on the DOUT pin. The falling edge of  $\overline{\text{SYNC}}$  disables the three-state on the DOUT pin, and data is clocked out on the falling edge of SCLK. Once  $\overline{\text{SYNC}}$  goes high, the three-state on the DOUT pin is enabled. The data input is sampled on the rising edge of SCLK and thus has to be valid a time,  $t_7$ , before this rising edge. The POLARITY pin may be used to change the SCLK edge which the data is sampled on and clocked out on. If resetting the interface is required, the  $\overline{\text{SYNC}}$  must be taken high and then low.

### Modes 4 and 5 (Self-Clocking Modes)

The timing diagrams in Figure 38 and Figure 39 are for Interface Modes 4 and 5. Interface Mode 4 has a noncontinuous SCLK output and Interface Mode 5 has a continuous SCLK output. These modes of operation are especially different to all the other modes since the SCLK and  $\overline{\text{SYNC}}$  are outputs. The  $\overline{\text{SYNC}}$  is generated by the part as is the SCLK. The master clock at the CLKIN pin is routed directly to the SCLK pin for Interface Mode 5 (Continuous SCLK) and the CLKIN signal is gated with the  $\overline{\text{SYNC}}$  to give the SCLK (noncontinuous) for Interface Mode 4.

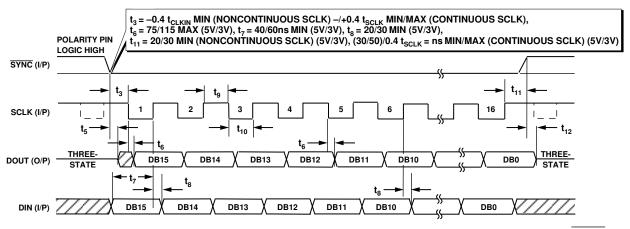


Figure 35. SPI/QSPI Mode 2 Timing Diagram for Read/Write Operation with DIN Input, DOUT Output and  $\overline{\text{SYNC}}$  Input (SM1 = SM2 = 0)

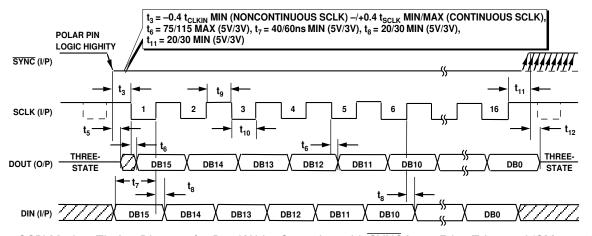


Figure 36. QSPI Mode 3 Timing Diagram for Read/Write Operation with  $\overline{SYNC}$  Input Edge Triggered (SM1 = 0, SM2 = 1)